

# SILICON PHOTODIODE VTP8840BTRH

#### FEATURES

- Surface mount package
- Low capacitance
- Fast response
- High shunt impedance
- Tape & reel supplied

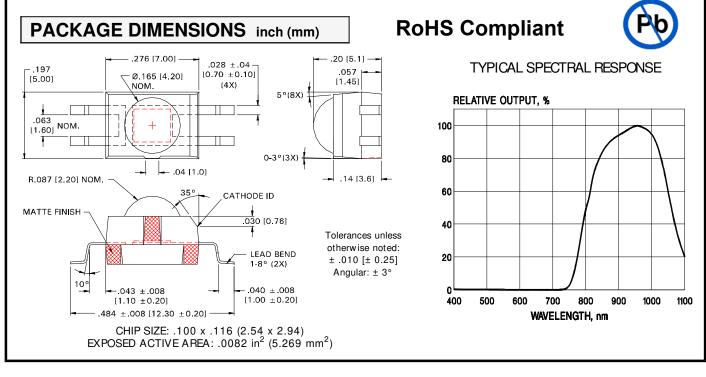
#### **PRODUCT DESCRIPTION**

This planar silicon photodiode features a lensed, visible blocking, IR transmitting package suitable for surface mount assembly in a "back mounted" (lens up) orientation.

These photodiodes exhibit performance charac teristics which make them suitable for a wide range of near-IR sensing applications. Devices are shipped taped & reeled on a 24 mm embossed carrier.

## **ELECTRO-OPTICAL CHARACTERISTICS** @ 25° C

PARAMETER	SYMBOL	MIN.	TYP.	MAX.	UNITS
SHORT CIRCUIT CURRENT @ 100 fc, 2850 K	Isc	50	60		μA
DARK CURRENT @ V <sub>R</sub> = 10 V	ID			20	nA
SHUNT RESISTANCE @ H = 0, V = 10 mV	Rsh		0.25		GΩ
JUNCTION CAPACITANCE @ V <sub>R</sub> = 3 V	CJ			50	pF
OPEN CIRCUIT VOLTAGE @ 100 fc, 2850 K	Voc	325			mV
ANGULAR RESPONSE (50% RESPONSE POINT)	θ1/2		±42		Degrees



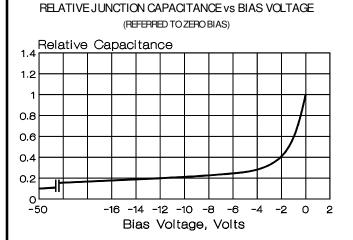
### GENERAL CHARACTERISTICS

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PARAMETER	SYMBOL	TYPICAL RATING	UNITS				
PEAK SPECTRAL RESPONSE @ 25°C	λp	925	nm				
RADIOMETRIC SENSITIVITY @ PEAK, 25°C	SRPK	0.6	A / W				
NOISE EQUIVALENT POWER	NEP	2.0 x 10 <sup>-13</sup>	W/ $\sqrt{Hz}$				
SPECIFIC DETECTIVITY	D*	1.2 x 10 <sup>12</sup>	cm $\sqrt{\text{Hz}}$ /W				
TEMPERATURE COEFFICIENT SHORT CIRCUIT CURRENT @ 2850 K SOURCE OPEN CIRCUIT VOLTAGE @ 2850 K SOURCE DARK CURRENT	TC Isc TC Voc TC I <sub>D</sub>	+0.22 - 2.0 +15.0	%/°C mV/ C %/°C				

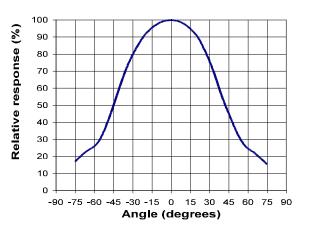
#### **ABSOLUTE MAXIMUM RATINGS**

PARAMETER	SYMBOL	RATING	UNITS
TEMPERATURE RANGE OPERATING AND STORAGE	T <sub>AMB</sub>	– 40 to +85	°C
LEAD SOLDER TEMPERATURE (1.6 mm FROM CASE, 5 SECONDS MAX.)	TLS	260°	°C
BREAKDOWN VOLTAGE @ 25°C	V <sub>BR</sub>	33	Volts
POWER DISSIPATION	PD	150	mW

# **TYPICAL CHARACTERISTIC CURVES**



#### ANGULAR RESPONSE



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